FAIRCHILD

SEMICONDUCTOR®

FDH5500_F085

N-Channel UltraFET Power MOSFET

55V, 75A, 7m Ω

Features

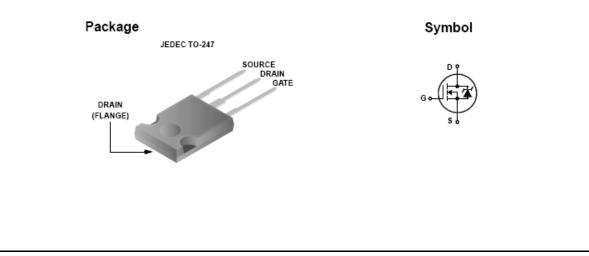
- Typ r_{DS(on)} = 5.2mΩ at V_{GS} = 10V, I_D = 75A
- Typ Q_{g(10)} = 118nC at V_{GS} = 10V
- Simulation Models
 -Temperature Compensated PSPICE and SABERTM Models
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Related Literature
 - -TB334, "Guidelines for Soldering Surface Mount Componets to PC Boards"
- Qualified to AEC Q101
- RoHS Compliant

Applications

- DC Linear Mode Control
- Solenoid and Motor Control
- Switching Regulators
- Automotive Systems

October 2008





MOSFET Maximum Rating	S $T_C = 25^{\circ}C$ unless otherwise noted
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Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage	(Note 1)	55	V
V _{DGR}	Drain to Gate Voltage (R_{GS} = 20k Ω)	(Note 1)	55	V
V _{GS}	Gate to Source Voltage	±20	V	
	Drain Current Continuous (T _C < 135 ^o C, V _{GS} = 10V)		75	Α
D	Pulsed		See Figure 4	A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	864	mJ
П	Power Dissipation		375	W
P _D	Dreate above 25°C		2.5	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	
ΤL	Max. Lead Temp. for Soldering (at 1.6mm from case for 10sec)		300	°C
T _{pkg}	Max. Package Temp. for Soldering (Package Body for 10sec)		260	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case	0.4	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient TO-247, 1in ² copper pad area	30	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDH5500	FDH5500_F085	TO-247	Tube	N/A	30 units

Electrical Characteristics T_{C} = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units

Off Characteristics

B _{VDSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} =$	$I_{D} = 250 \mu A, V_{GS} = 0V$		-	-	V
1	Zara Cata Valtaga Drain Current	V_{DS} = 50V, V_{GS} =	0V	-	-	1	
DSS	I _{DSS} Zero Gate Voltage Drain Current	V _{DS} = 45V	$T_{\rm C} = 150^{\rm o}{\rm C}$	-	-	250	μΑ
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	2	2.9	4	V
r _{DS(on)}	Drain to Source On Resistance	I _D = 75A, V _{GS} = 10V	-	5.2	7	mΩ

Dynamic Characteristics

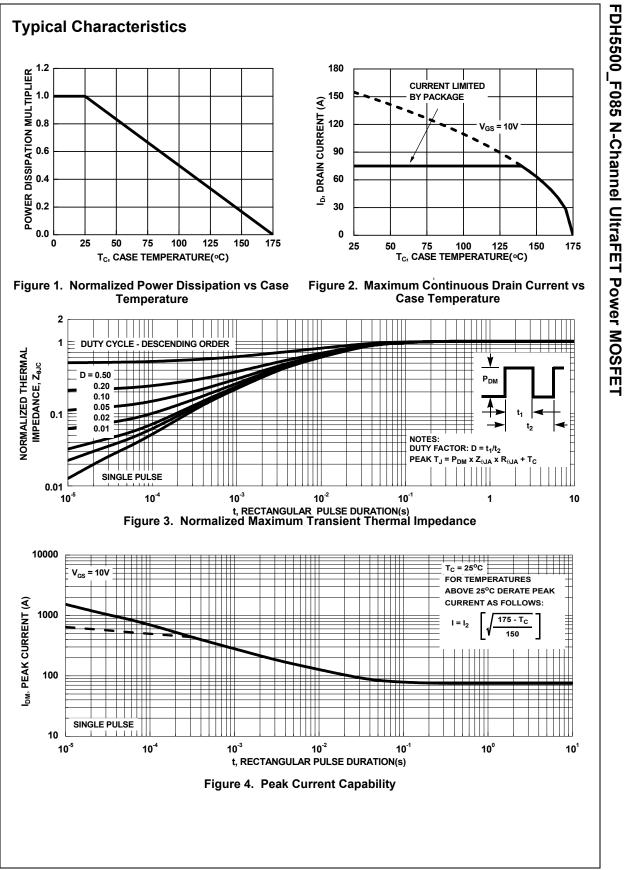
Ciss	Input Capacitance		$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz		3565	-	pF
C _{oss}	Output Capacitance	── V _{DS} = 25V, V _{GS} = f = 1MHz			1310	-	pF
C _{rss}	Reverse Transfer Capacitance			-	395	-	pF
Q _{g(TOT)}	Total Gate Charge at 20V	V _{GS} = 0 to 20V		-	206	268	nC
Q _{g(10)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V	$V_{DD} = 30V$	-	118	153	nC
Q _{g(TH)}	Threshold Gate Charge	V _{GS} = 0 to 2V	$I_D = 75A$ $R_1 = 0.4\Omega$	-	6.2	8.1	nC
Q _{gs}	Gate to Source Gate Charge		$I_0 = 1.0 \text{mA}$	-	17.8	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		y -	-	51	-	nC

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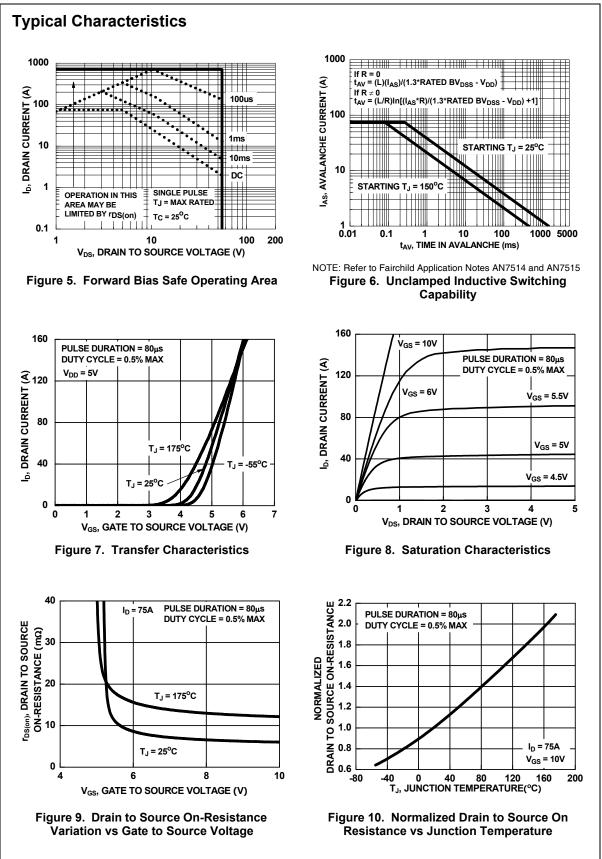
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ing Characteristics					
t _{on}	Turn-On Time		-	-	185	ns
t _{d(on)}	Turn-On Delay Time		-	13.7	-	ns
t _r	Rise Time	$V_{DD} = 30V, I_D = 75A,$	-	102	-	ns
t _{d(off)}	Turn-Off Delay Time	$\frac{R_{L} = 0.4\Omega, V_{GS} = 10V,}{R_{GS} = 2.5\Omega}$	-	34	-	ns
t _f	Fall Time		-	22	-	ns
t _{off}	Turn-Off Time		-	-	91	ns
V _{SD}	OURCE DIODE Characteristics	I _{SD} = 75A	-	1	1.25	V
t _{rr}	Reverse Recovery Time	I _E = 75A, dI _{SD} /dt = 100A/μs	-	60	78	ns
Q _{rr}	Reverse Recovery Charge		-	77	100	nC

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This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

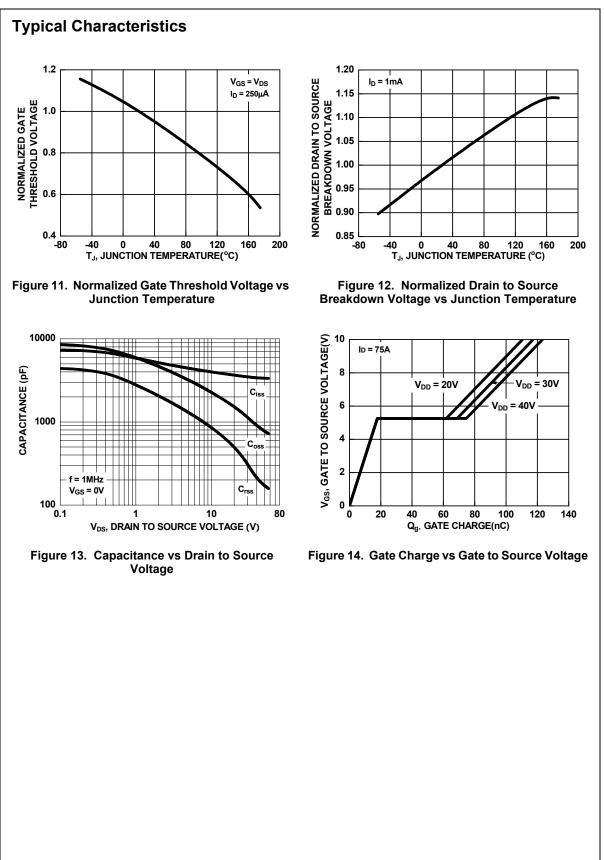


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